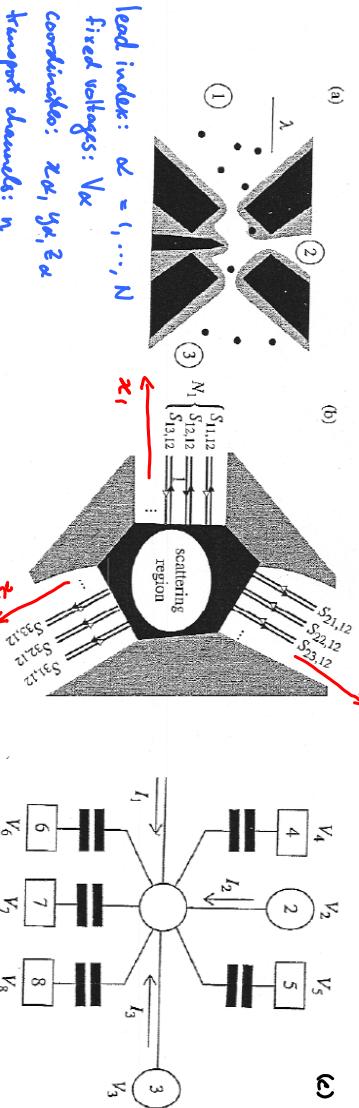


## 1.5 Multi-terminal circuits (MTC)

7.5.2010

(MTC1)



Multiterminal circuit: (a) There are eight electrodes connected to this nanostucture: five gates and three terminals. (b) Structure of multi-terminal scattering matrix. We show amplitudes of the wave coming in the second channel of the first terminal.

$$\psi(x_R, y_R, z_R) \quad (SM2) = \sum_m \frac{1}{\sqrt{2\pi k_R v_R}} \hat{\Phi}_m(y_R, z_R) [a_m e^{-ik_R^{(m)} x_R} + b_m e^{+ik_R^{(m)} x_R}] \quad (1)$$

generate.

$$\psi(x_\alpha, y_\alpha, z_\alpha) = \sum_m \frac{1}{\sqrt{2\pi k_R v_R}} \hat{\Phi}_{mN}(y_\alpha, z_\alpha) [a_{mN} e^{-ik_R^{(mN)} x_\alpha} + b_{mN} e^{+ik_R^{(mN)} x_\alpha}] \quad (2)$$

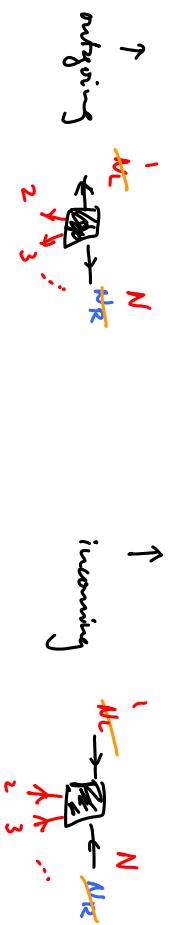
$$k_R^{(mN)} = \sqrt{2m(E - E_{mN})/t} \quad (3)$$

Circuit diagram

(MTC2)

$$b_{\alpha n} = \sum_{\beta=1}^N \sum_{m=1}^{N_B} S_{\alpha n, \beta m} a_{\beta m} \quad \alpha = L, R, 1, \dots, N \quad (1)$$

$$m = 1, \dots, N_B$$



$$\text{Unitarity: } \hat{S}^\dagger \hat{S} = \hat{1} \quad , \quad \hat{S} \hat{S}^\dagger = \hat{1} \quad (2)$$

$$\begin{aligned} \hat{S}_{\alpha\alpha} &: \text{reflection in lead } \alpha \\ \hat{S}_{\alpha\beta} &: \text{transmission from lead } \beta \rightarrow \text{lead } \alpha \end{aligned} \quad (3) \quad (4)$$

$$\text{Time reversibility: } \hat{S}(B) \quad (SM2) \quad \hat{S}^\dagger(-B) \quad \xrightarrow{\text{general}} S_{\alpha n, \beta m}(B) = S_{\beta m, \alpha n}(-B) \quad (5)$$

### Multi-terminal Landauer formula



Current in lead  $\alpha$ ,  
at  $x_\alpha = \infty$ :  $I_\alpha = 2s e \sum_n \int_{-\infty}^{\infty} \frac{dk_x^{(\alpha n)}}{2\pi} v_x(k_x) f(k_x^{(\alpha n)})$  (1)

$k_x^{(\alpha n)} < 0$	$k_x^{(\alpha n)} > 0$	comes from $\alpha, \beta$	with probability $ S_{\alpha n, \beta n} ^2$	$f_n(k_x)$ $f_\alpha(E)$ $f_\beta(E)$
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$$(SMR.D) I_\alpha = 2s e \sum_n \int_{-\infty}^{\infty} dk_x v_x(k_x) \left[ -f_\alpha(E) + \sum_{\beta} |S_{\alpha n, \beta n}|^2 f_\beta(E) \right] \quad (4)$$

$$= -\frac{1}{e} g_\alpha \sum_n \int dE \sum_{\beta} [S_{\alpha \beta} S_{\alpha \beta}^* - |S_{\alpha n, \beta n}|^2] f_\beta(E) \quad (5)$$

$$I_\alpha = -\frac{1}{e} g_\alpha \int dE \sum_{\beta} \underbrace{\text{Tr} \{ S_{\alpha \beta} - S_{\beta \alpha}^* S_{\alpha \beta} \}}_{\uparrow \text{over channels}} f_\beta(E) \quad (6)$$

Current conservation: (total current in all terminals vanishes) (MTC 4)

$$\sum_{\alpha} I_\alpha = -\frac{g_\alpha}{e} \int dE \sum_{\beta} T_{\alpha \beta} \left\{ 1 - \frac{(S^+ S^-)_{\alpha \beta}}{S_{\alpha \alpha}} \right\} f_\beta(E) = 0 \quad (7)$$

unitarity:

$\sum_{\beta} = 1$

Linear regime: apply small voltage only to one lead, say  $V$

$$\frac{\mu_\gamma}{\mu_\beta} = \varepsilon_F + eV \quad , \quad \frac{\mu_\beta}{\mu_\gamma} = \varepsilon_F \quad \forall \beta \neq \gamma$$

$$f_\beta(E) = [e^{\beta(E - \mu_\beta)} + 1]^{-1} \quad (\text{gives } 0, \text{ since } T_{\alpha \beta} (1 - (S^+ S^-)_{\alpha \beta}) = 0)$$

$$I_\alpha = -\frac{1}{e} g_\alpha \int dE \sum_{\beta} \text{Tr} \{ S_{\alpha \beta} - \hat{S}_{\beta \alpha}^* \hat{S}_{\alpha \beta} \} (f_\beta(E) - f(E))$$

if  $\hat{S}_{\alpha \beta}$  is  $E$ -independent on scale of  $eV$ :

$$I_\alpha = -g_\alpha \text{Tr} [S_{\alpha \beta} - \hat{S}_{\beta \alpha}^* \hat{S}_{\alpha \beta}] V = g_\alpha V \quad \text{"multi-terminal Landauer formula"} \quad (8)$$

In linear regime, contributions to  $I_d$  from all leads with  $V_\beta \neq 0$  add up: MTC5

$$I_d = \sum_{\beta} g_{d\beta} V_\beta \quad [g_{d\beta} : \text{elements of "conductance matrix"}] \quad (1)$$

$$\text{Current conservation: } 0 = \sum_{\alpha} I_{\alpha} \quad \text{for arbitrary } V_\beta \Rightarrow \sum_{\alpha} g_{d\beta} = 0 + \beta \quad (2)$$

Time reversibility (2.5) implies:

$$S_{\alpha n, \beta m}(B) = S_{\beta m, \alpha n}(-B)$$

$$g_{d\beta}(B) = g_{\beta d}(-B) \quad \text{"Onsager relations" (3)}$$

For  $B = 0$ ,  $g_{d\beta}$  is symmetric; # of independent parameters then:

(2)  $\Rightarrow$  only  $(N-1)$  indep. parameters per column. since  $g$  is symmetric  
 $(N-1)$  diagonal elements, and  $[(N-1)^2 - (N-1)]/2$  off-diag are independent.

$$\text{In total: } [(N-1)^2 + (N-1)]/2 = N(N-1)/2$$

For  $N=2$ : only 1 independent element:

$$g = g_{d\alpha} = g_{R\alpha} = -g_{\alpha L} = -g_{R\alpha}$$

$$\boxed{\begin{array}{c} \text{Check} \\ \text{Signs:} \\ \begin{array}{ccc} V_L \neq 0 & \xrightarrow{\text{---}} & g_{RL} = -g_{LL} > 0 \\ \xleftarrow{\text{---}} & & \xleftarrow{\text{---}} g_{\alpha L} \\ x_L & \leftarrow & x_R \\ I_L < 0 & & I_R > 0 \end{array} \end{array}}$$

Resistance matrix  $R_{d\beta}$ :

$$\text{defined by: } V_\alpha = \sum_{\beta} R_{d\beta} I_\beta \quad \stackrel{(5.1)}{\Rightarrow} \quad R = g^{-1} \quad (1)$$

$$R_{d\beta}(B) = R_{\beta d}(-B) \quad \text{"Onsager relations" (2)}$$

## Voltage probes and two-terminal measurements (R. Landauer)

MTCF

Ideal voltage probe:

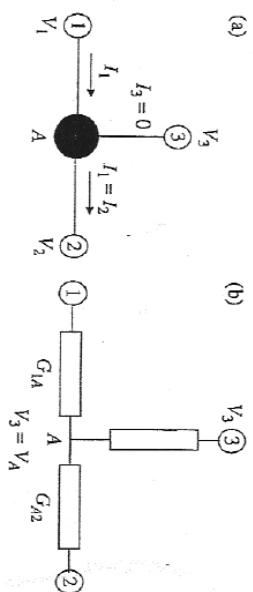
non-invasive, does not

draw current!

$$I_{\alpha} = \sum_{\beta} g_{\alpha\beta} V_{\beta}$$

$$\sigma = \sum_{\beta} g_{\alpha\beta}$$

(a) Three-terminal circuit with terminal 3 as a voltage probe. (b) A classical circuit could be presented in this way, and conductances of the elements  $g_{1A}, g_{A2}$  can be determined from the voltage  $V_3$  measured. (5.2)



$$0 = I_3 = g_{31}V_1 + g_{32}V_2 + \underbrace{g_{33}V_3}_{\uparrow \text{for ideal voltmeter}} = g_{31}(V_1 - V_3) + g_{32}(V_2 - V_3) \quad (1)$$

$$\text{Solve: } V_3 = \frac{g_{31}V_1 + g_{32}V_2}{g_{31} + g_{32}} \stackrel{(4.5)}{=} \frac{V_1 T_r(g_{12}^+ \hat{s}_{31}) + V_2 T_r(\hat{s}_{23}^+ \hat{s}_{32})}{T_r(s_{13}^+ \hat{s}_{31}) + T_r(\hat{s}_{23}^+ \hat{s}_{32})} \quad (2)$$

"Noninvasive measurement" requires:  $g_{31}, g_{32} \ll g_{12}$ , or  $\hat{s}_{31}, \hat{s}_{32} \rightarrow 0$ . Then  $V_3$  remains finite!

Finite  $V_3$  is also obtained in classical circuit model:  
Consider  $g_{1A}$  and  $g_{A2}$  in series,  $V_3 = V_A$ , then

$$\frac{g_{1A}}{g_{12}} = \frac{V_1 - V_2}{V_1 - V_A} \quad (1a) \quad \frac{g_{A2}}{g_{12}} = \frac{V_2 - V_1}{V_2 - V_A} \quad (1b)$$

$\Rightarrow g_{1A}, g_{A2}$  can be measured by measuring  $V_1, V_2, V_A$ .

Consistency checks: Solve for  $V_A$ :

$$(V_1 - V_A)g_{1A} = g_{12}(V_1 - V_2) \Rightarrow V_A = \frac{1}{g_{1A}}[V_1(g_{1A} - g_{12}) + g_{12}V_2] \quad (2a)$$

$$(V_2 - V_A)g_{A2} = g_{12}(V_2 - V_1) \Rightarrow V_A = \frac{1}{g_{A2}}[V_2(g_{A2} - g_{12}) + g_{12}V_1] \quad (2b)$$

$$(2a) = (2b) \Rightarrow R_{1A} \left[ V_1 \left( \frac{1}{R_{1A}} - \frac{1}{R_{12}} \right) + \frac{V_2}{R_{12}} \right] = R_{A2} \left[ V_2 \left( \frac{1}{R_{A2}} - \frac{1}{R_{12}} \right) + \frac{V_1}{R_{12}} \right] \quad (3)$$

$$\Rightarrow V_1 \left[ 1 - \frac{R_{1A} + R_{A2}}{R_{12}} \right] = V_2 \left[ 1 - \frac{R_{A2} + R_{1A}}{R_{12}} \right] \quad (4)$$

(4) must hold for any  $V_1, V_2 \Rightarrow R_{1A} + R_{A2} = R_{12} \quad \square$

Difference in descriptions:

Classical: we can apply a voltage to any point in circuit, including A

Quantum: we can apply voltage only to memory; if A represents a nanostructure (e.g. single-channel conductance), it is too small to apply a voltage directly to it.

Let's see what happens if we try to assign voltages "inside a nanostructure":

If we write  $R_{\text{tot}} = R_{1A} + R_{AB} + R_{B2}$ , what is  $R_{AB}$ ?

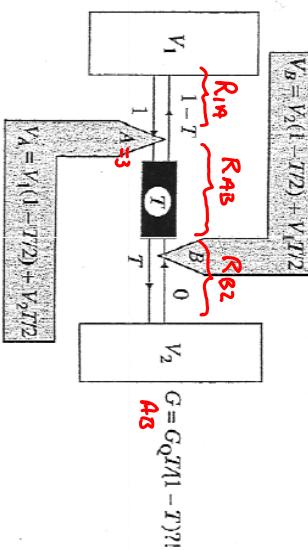
In this classical picture, we would have (in analogy to (2.1)):

$$g_{1A} = g_{12} \frac{V_1 - V_2}{V_1 - V_A} \quad (1)$$

$$g_{AB} = g_{12} \frac{V_1 - V_2}{V_A - V_B} \quad (2)$$

$$g_{B2} = g_{12} \frac{V_1 - V_2}{V_B - V_2} \quad (3)$$

So: First determine  $V_A$ ,  $V_B$ , then we get  $g_{AB}$  from (2).



Let us get  $V_A = V_3$  from (2.2):

$$V_A = V_3 \stackrel{(2.2)}{=} \frac{g_{31} V_1 + g_{32} V_2}{g_{31} + g_{32}} \quad (1)$$

We first need:

$$g_{31} = g_{A1} = g_A [\omega + (1-\tau)(1-\omega)\omega] \approx$$

$$\approx g_A \omega(1-\tau) \quad (2a)$$

$$g_{32} = g_{A2} = g_A \omega T \quad (2b)$$

$$(2) \text{ into } (1): \quad V_A = \frac{(2-\tau)\omega + \tau V_2}{(2-\tau) + \tau} = (1 - \tau/2)V_1 + \tau/2 V_2 \stackrel{!!}{\neq} V_1 \quad (3a)$$

$$\text{Similarly: } V_B = (1 - \tau/2)V_2 + \tau/2 V_1 \stackrel{!!}{\neq} V_2 \quad (3b)$$

That  $V_A \neq V_1$  is a consequence of pretending that voltage  $V_A$  can be applied directly inside nanostructure ...

MTC 9

Let us proceed nevertheless and insert  $V_A$ ,  $V_B$  from (10.2) into (9.1-3): MTC9

$$I \rightarrow A: \quad g_{IA}^{(4,1)} = \frac{g_{12}}{V_1 - V_2} \frac{V_1 - V_2}{V_1 - V_A} \stackrel{(8.3a)}{=} \frac{g_{\alpha T}}{\sqrt{V_1 - [(1-T/2)V_1 + T/2V_2]}} = 2g_{\alpha} \quad (1)$$

$$\begin{aligned} A \rightarrow B: \quad g_{AB}^{(4,2)} &= \frac{g_{12}}{V_1 - V_2} \frac{V_1 - V_2}{V_A - V_B} \stackrel{(8.3)}{=} \frac{g_{\alpha T}}{V_1 - V_2} \frac{[(1-T/2)V_1 + T/2V_2] - [(1-T/2)V_2 + T/2V_1]}{[V_1 - V_2]} \\ &= \frac{g_{\alpha T}}{1-T} \quad (\# \quad g_{\alpha T} = \text{two-terminal Landauer formula} !!) \end{aligned} \quad (2)$$

$$B \rightarrow 2: \quad g_{B2}^{(4,3)} = \frac{g_{12}}{V_1 - V_2} \frac{V_1 - V_2}{V_B - V_2} = \frac{g_{\alpha T}}{V_1 - V_2} \frac{[(1-T/2)V_2 + T/2V_1] - V_2}{[(1-T/2)V_2 + T/2V_1]} = 2g_{\alpha} \quad (3)$$

Consistency check:

$$R_{tot} = R_{IA} + R_{AB} + R_{B2} = \frac{1}{g_{IA}} + \frac{1}{g_{AB}} + \frac{1}{g_{B2}} = \frac{1}{g_{\alpha T}} \left[ \frac{1}{2} + \frac{1-T}{T} + \frac{1}{2} \right] = \frac{1}{g_{\alpha T}} = \frac{1}{g_{tot}} \quad (4)$$

MTC16

Comments:

- $\underline{g_{AB} = \frac{g_{\alpha T}}{1-T}}$   $\neq g_{\alpha T}$  as expected from Landauer formula  
 $\underline{=}$  "wrong Landauer formula"

- For QPC with  $T=1$ :  $\underline{g_{AB} \rightarrow \infty}$  or  $R_{AB} = \underline{g_{AB}^{-1} \rightarrow 0}$

This does make sense: QPC has no resistance and no voltage drop across it!

- Voltage drops across  $R_{IA} = \frac{1}{g_{IA}} = \frac{1}{2g_{\alpha}}$  and  $R_{IB} = \frac{1}{g_{IB}} = \frac{1}{2g_{\alpha}}$

(called "contact resistances" by Landauer).

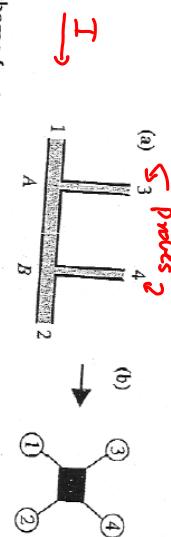
- What went wrong: in reality, it is not possible to apply voltages  $V_A$  and  $V_B$  to a single-channel scatterer. Voltages can be applied only to reservoirs. It is not possible to separate nanostructure into separate elements of definite resistance.

- Tunnel junction:  $T \ll 1$ :  $\underline{g_{AB} \approx g_{\alpha T} = g_{tot}}$  as expected.

Reason: voltage drop across tunnel junction, contribution of contact resistances is  $\approx 0$

If Eqs. (II.1) - (II.3) are to hold, we need a 4-terminal circuit:

(MTC 13)



A common scheme for two-probe measurement of the resistance  $R_{AB}$ , (a) does not generally work in quantum transport. The reason is that the equivalent four-terminal nanostructure (b) cannot be generally separated into elements of definite resistance.

Classically: terminals 1 & 2 pass current

terminals 3 & 4 probe voltage drop between A & B

$$\text{we expect } R_{AB} = \frac{V_3 - V_4}{I}$$

Quantum transport: This does not work in general!

E.g. assume non-invasive voltage probes:

$$g_{43}, g_{34} \ll g_{41}, g_{42}$$

$$g_{31}, g_{32} \ll g_{12}, g_{21}$$

Using  $I_a^{(5.1)} = \sum_p g_{ap} V_p$ ,  $\stackrel{(5.2)}{=}$   $\sum_p g_{ap}$  MTCL14

$$(1)$$

we get from  $0 = I_3 = g_{31}V_1 + g_{32}V_2 + \cancel{g_{33}V_3}$

$$0 = I_4 = g_{41}V_1 + g_{42}V_2 + \cancel{g_{44}V_4}$$

$$V_3 - V_4 = (V_1 - V_2) \left( \frac{g_{31}}{\cancel{g_{31} + g_{32}}} - \frac{\cancel{g_{41}}}{\cancel{g_{41} + g_{42}}} \right) \quad (2)$$

Current:  $I = g_{41}(V_1 - V_2)$

$$R = \frac{V_3 - V_4}{I} = \frac{1}{g_{21}} \left( \frac{g_{31}}{\cancel{g_{31} + g_{32}}} - \frac{\cancel{g_{41}}}{\cancel{g_{41} + g_{42}}} \right) \neq R_{AB} \quad (4)$$

Note also  $R(\beta) \neq R(-\beta)$  : Onsager relations do not hold in multi-terminal setup.